Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	117	gate adj electrode same auxiliary adj electrode same semiconductor	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/13 11:58
L2	78	semiconductor and auxiliary near1 (electrode or gate) and (soi or silicon adj on adj insulator)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	OFF	2005/11/13 12:00